

Overview

- Automatic adjustment of exposure time for precise detection on changing materials
- High immunity to ambient light for reliable detection regardless of ambient conditions
- Line beam shape for particularly robust detection results on structured surfaces



Picture similar



Technical data

General data

Type	Background suppression
Sensing distance T_w	50 ... 550 mm
Sensing range T_b	50 ... 550 mm
Repeat accuracy	2 ... 86 μ m
Power on indication	LED green
Output indicator	LED red
Beam type	Line

Light Source

Light source	Pulsed red laser diode
Laser class	2
Wave length	660 nm
Maximum pulse power	2 mW
Pulse duration	0.001 ... 1.2 ms
Pulse period	0.2 ... 3.4 ms

Electrical data

Response time / release time	< 6.7 ms
Voltage supply range +Vs	12 ... 28 VDC
Current consumption max. (no load)	50 mA
Output function	Light / dark operate
Output circuit	PNP

Electrical data

Output current	< 100 mA
Short circuit protection	Yes
Reverse polarity protection	Yes, Vs to GND

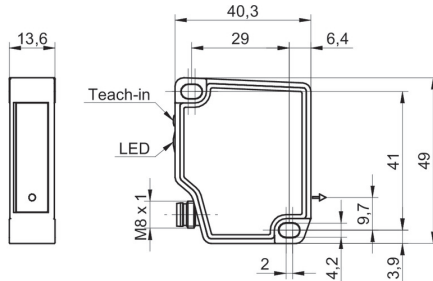
Mechanical data

Width / diameter	13.6 mm
Height / length	49 mm
Depth	40.3 mm
Housing material	Die-cast zinc
Front (optics)	Glass
Connection types	Connector M8 4 pin
Weight	67 g

Ambient conditions

Ambient light immunity	< 100 kLux
Protection class	IP 67
Operating temperature	-10 ... +50 °C
Storage temperature	-20 ... +60 °C
Vibration (sinusoidal)	IEC 60068-2-6:2008 1 mm p-p at f = 10 - 55 Hz, duration 5 min per axis 30 min endurance at f = 55 Hz per axis
Shock (semi-sinusoidal)	IEC 60068-2-27:2009 30 g / 11 ms, 6 jolts per axis and direction

Dimension drawing



Laser warning



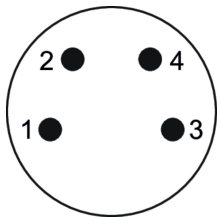
LASER RADIATION
DO NOT STARE INTO BEAM
Wavelength: 640...670nm
IEC 60825-1, Ed. 3, 2014
CLASS 2 LASER PRODUCT

IEC 60825-1/2014 Complies with 21 CFR 1040.10 and 1040.11 except for conformance with IEC 60825-1 Ed. 3., as described in Laser Notice No. 56, dated May 8, 2019

Connection diagram



Pin assignment



Beam characteristic (typically)

